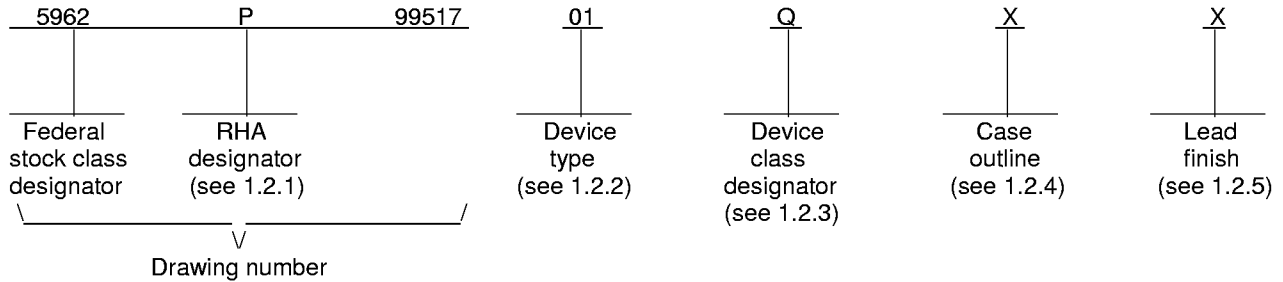


REVISIONS																			
LTR	DESCRIPTION														DATE (YR-MO-DA)	APPROVED			
A	Add device types 03 and 04. -rrp														99-11-15	R. Monnin			
REV																			
SHEET																			
REV	A	A	A	A															
SHEET	15	16	17	18															
REV STATUS OF SHEETS				REV	A	A	A	A	A	A	A	A	A	A	A	A	A	A	
				SHEET	1	2	3	4	5	6	7	8	9	10	11	12	13	14	
PMIC N/A				PREPARED BY Rajesh Pithadia					DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216										
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Rajesh Pithadia															
				APPROVED BY Raymond Monnin					MICROCIRCUIT, LINEAR, RADIATION HARDENED, ADJUSTABLE, VOLTAGE REGULATOR, MONOLITHIC SILICON										
				DRAWING APPROVAL DATE 99-05-13															
				REVISION LEVEL A					SIZE A	CAGE CODE 67268	5962-99517								
					SHEET 1 OF 18														

1. SCOPE

1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN is as shown in the following example:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
01	LM137H	Adjustable, negative, voltage regulator
02	LM137K	Adjustable, negative, voltage regulator
03	LM117H	Adjustable, positive, voltage regulator
04	LM117K	Adjustable, positive, voltage regulator

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

<u>Device class</u>	<u>Device requirements documentation</u>
M	Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A
Q or V	Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
X	See figure 1	3	TO-39 Can
Y	MBFM1-P2	2	Flange mount

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

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1.3 Absolute maximum ratings. ^{1/}

Minimum input voltage (V _{IN}):	
Device types 01 and 02	-41.25 V
Device types 03 and 04	41.25 V
Input-output voltage differential	40 V
Power dissipation:	Internally limited ^{2/}
Maximum power dissipation at T _A = 25°C:	
Device type 01	2.5 W
Device type 02	28 W
Device type 03	2 W
Device type 04	20 W
Storage temperature range	-65°C to +150°C
Lead temperature (soldering, 10 seconds).....	300°C
Maximum junction temperature (T _J).....	150°C ^{2/}
Operating junction temperature	-55°C to +150°C
Thermal resistance, junction-to-case (θ _{JC}):	
Case X at 1.0 W (device type 01)	15°C/W
Case Y (device type 02)	4°C/W
Case X (device type 03)	21°C/W
Case Y (device type 04)	1.9°C/W
Thermal resistance, junction-to-ambient (θ _{JA}):	
Case X (device type 01).....	140°C/W Still air at 0.5 W 64°C/W 500 LFPM air flow at 0.5 W
Case Y (device type 02).....	40°C/W Still air 14°C/W 500 LFPM air flow
Case X (device type 03).....	186°C/W Still air 64°C/W 500 LFPM air flow
Case Y (device type 04).....	39°C/W Still air 14°C/W 500 LFPM air flow

1.4 Recommended operating conditions.

Input voltage range:	
Device types 01 and 02	-4.25 V to -41.25 V
Device types 03 and 04	4.25 V to 41.25 V
Ambient operating temperature range (T _A).....	-55°C to +125°C

1.5 Radiation features.

Maximum total dose available (dose rate = 50 – 300 rads (Si)/s):	
Device classes Q and V (device types 01 and 02)	30 Krads
Device classes Q and V (device types 03 and 04)	100 Krads

^{1/} Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

^{2/} The maximum power dissipation must be derated at elevated temperatures and is dictated by T_J, θ_{JA}, and T_A. The maximum allowable power dissipation at any temperature is P_D = (T_{JMAX} – T_A)/θ_{JA} or the number given in the absolute maximum ratings, whichever is lower.

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2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solicitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-973 - Configuration Management.
MIL-STD-1835 - Interface Standard For Microcircuit Case Outlines.

HANDBOOKS

DEPARTMENT OF DEFENSE

MIL-HDBK-103 - List of Standard Microcircuit Drawings (SMD's).
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein and figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Radiation exposure circuit. The radiation exposure circuit shall be as specified on figure 3.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/ 2/ -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit			
					Min	Max				
Output voltage	V _{OUT}	V _{IN} = -4.25 V, I _L = 5 mA	1	01, 02	-1.275	-1.225	V			
			2, 3		-1.3	-1.2				
		V _{IN} = -4.25 V, I _L = 500 mA	1	01	-1.275	-1.225				
			2, 3		-1.3	-1.2				
		V _{IN} = -4.25 V, I _L = 1.5 A	1	02	-1.275	-1.225				
			2, 3		-1.3	-1.2				
		V _{IN} = -41.25 V, I _L = 5 mA	1	01, 02	-1.275	-1.225				
			2, 3		-1.3	-1.2				
		V _{IN} = -41.25 V, I _L = 50 mA	1	01	-1.275	-1.225				
			2, 3		-1.3	-1.2				
		V _{IN} = -41.25 V, I _L = 200 mA	1	02	-1.275	-1.225				
			2, 3		-1.3	-1.2				
Line regulation	V _{RLINE}	V _{IN} = -41.25 V to -4.25 V, I _L = 5 mA	1	01, 02	-9	9	mV			
			2, 3		-23	23				
Load regulation	V _{RLOAD}	V _{IN} = -6.25 V, I _L = 5 mA to 500 mA	1	01	-12	12	mV			
			2, 3		-24	24				
		V _{IN} = -41.25 V, I _L = 5 mA to 50 mA	1	01	-6	6				
			2, 3		-12	12				
		V _{IN} = -6.25 V, I _L = 5 mA to 200 mA	1	01	-6	6				
			2, 3		-12	12				
		V _{IN} = -6.25 V, I _L = 5 mA to 1.5 A	1	02	-6	6				
			2, 3		-12	12				
		V _{IN} = -41.25 V, I _L = 5 mA to 200 mA	1	02	-6	6				
			2, 3		-12	12				
		Thermal regulation	V _{rth}	V _{IN} = -14.6 V, I _L = 500 mA	1	01		-5	5	mV
				V _{IN} = -14.6 V, I _L = 1.5 A	1	02		-5	5	
Adjust pin current	I _{adj}	V _{IN} = -4.25 V, I _L = 5 mA	1, 2, 3	01, 02	25	100	μA			
		V _{IN} = -41.25 V, I _L = 5 mA			25	100				
Adjust pin current change vs. line voltage	ΔI _{adj} (line)	V _{IN} = -41.25 V to -4.25 V, I _L = 5 mA	1, 2, 3	01, 02	-5	5	μA			
			M, D, P		1	-10		10		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Adjust pin current change vs. load current	ΔI_{adj} (load)	$V_{IN} = -6.25$ V, $I_L = 5$ mA to 500 mA	1, 2, 3	01	-5	5	μ A
		$V_{IN} = -6.25$ V, $I_L = 5$ mA to 1.5 A		02	-5	5	
Output short circuit current	I_{OS}	$V_{IN} = -4.25$ V	1, 2, 3	01	0.5	1.8	A
		$V_{IN} = -40$ V			0.05	0.5	
		$V_{IN} = -4.25$ V		02	1.5	3.5	
		$V_{IN} = -40$ V			0.2	1	
Output voltage recovery after output short circuit current	V_{OUT} (Recovery)	$V_{IN} = -4.25$ V	1	01, 02	-1.275	-1.225	V
					2, 3	-1.3	
		$V_{IN} = -40$ V	1	-1.275	-1.225		
			2, 3	-1.3	-1.2		
Minimum load current	I_q	$V_{IN} = -4.25$ V	1, 2, 3	01, 02	0.2	3	mA
		$V_{IN} = -14.25$ V			0.2	3	
		$V_{IN} = -41.25$ V			1	5	
Voltage start-up	V_{start}	$V_{IN} = -4.25$ V, $I_L = 500$ mA	1	01	-1.275	-1.225	V
					2, 3	-1.3	
		$V_{IN} = -4.25$ V, $I_L = 1.5$ A	1	02	-1.275	-1.225	
			2, 3		-1.3	-1.2	
Output voltage <u>3/</u>	V_{OUT}	$V_{IN} = -6.25$ V, $I_L = 5$ mA	2	01, 02	-1.3	-1.2	V
Ripple rejection	$\Delta V_{IN}/\Delta V_{OUT}$	$V_{IN} = -6.25$ V, $I_L = 125$ mA, $e_i = 1$ V _{rms} at 2400 Hz	4	01	48		dB
		$V_{IN} = -6.25$ V, $I_L = 500$ mA, $e_i = 1$ V _{rms} at 2400 Hz		02	50		
Output noise voltage	V_{no}	$V_{IN} = -6.25$ V, $I_L = 50$ mA	7	01		120	μ V _{rms}
		$V_{IN} = -6.25$ V, $I_L = 100$ mA		02		120	
Line transient response	$\Delta V_{OUT}/\Delta V_{IN}$	$V_{IN} = -6.25$ V, $V_{PULSE} = -1$ V, $I_L = 50$ mA	7	01		80	mV/V
		$V_{IN} = -6.25$ V, $V_{PULSE} = -1$ V, $I_L = 100$ mA		02		80	
Load transient response	$\Delta V_{OUT}/\Delta I_L$	$V_{IN} = -6.25$ V, $I_L = 50$ mA, $\Delta I_L = 200$ mA	7	01		60	mV
		$V_{IN} = -6.25$ V, $I_L = 100$ mA, $\Delta I_L = 400$ mA		02		60	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/ 2/ -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Output voltage	V _{OUT}	V _{IN} = 4.25 V, I _L = -5 mA	1,2,3	03, 04	1.2	1.3	V
			M,D,P,L,R		1	1.2	
		V _{IN} = 4.25 V, I _L = -500 mA	1,2,3	03	1.2	1.3	
			M,D,P,L,R		1	1.2	
		V _{IN} = 4.25 V, I _L = -1.5 A	1,2,3	04	1.2	1.3	
			M,D,P,L,R		1	1.2	
		V _{IN} = 41.25 V, I _L = -5 mA	1,2,3	03, 04	1.2	1.3	
			M,D,P,L,R		1	1.2	
		V _{IN} = 41.25 V, I _L = -50 mA	1,2,3	03	1.2	1.3	
			M,D,P,L,R		1	1.2	
		V _{IN} = 41.25 V, I _L = -200 mA	1,2,3	04	1.2	1.3	
			M,D,P,L,R		1	1.2	
Line regulation	V _{RLINE}	V _{IN} = 4.25 V to 41.25 V I _L = -5 mA	1	03, 04	-9	9	mV
			2, 3		-23	23	
			M,D,P,L,R		1	-18	
Load regulation	V _{RLOAD}	V _{IN} = 6.25 V, I _L = -500 mA to -5 mA	1,2,3	03	-12	12	mV
			1,2,3		-12	12	
		V _{IN} = 6.25 V, I _L = -1.5 A to -5 mA	1	04	-3.5	3.5	
			2, 3		-12	12	
		M,D,P,L,R	1	-5.5	5.5		
			V _{IN} = 41.25 V, I _L = -200 mA to -5 mA	1	-3.5	3.5	
		2, 3		-12	12		
		M,D,P,L,R	1	-5.5	5.5		
Thermal regulation	V _{rth}	V _{IN} = 14.6 V, I _L = -500 mA	1	03	-12	12	mV
		V _{IN} = 14.6 V, I _L = -1.5 A	1	04	-12	12	
Adjust pin current	I _{adj}	V _{IN} = 4.25 V, I _L = -5 mA	1, 2, 3	03, 04	-100	-15	μA
		V _{IN} = 41.25 V, I _L = -5 mA			-100	-15	
Adjust pin current change vs. line voltage	ΔI _{adj} (line)	V _{IN} = 4.25 V to 41.25 V, I _L = -5 mA	1, 2, 3	03, 04	-5	5	μA

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Adjust pin current change vs. load current	ΔI_{adj} (load)	$V_{IN} = 6.25\text{ V}$, $I_L = -500\text{ mA}$ to -5 mA	1, 2, 3	03	-5	5	μA
		$V_{IN} = 6.25\text{ V}$, $I_L = -1.5\text{ A}$ to -5 mA		04	-5	5	
Output short circuit current	I_{os}	$V_{IN} = 4.25\text{ V}$	1, 2, 3	03	-1.8	-0.5	A
		$V_{IN} = 40\text{ V}$			-0.5	-0.05	
		$V_{IN} = 4.25\text{ V}$		04	-3.5	-1.5	
		$V_{IN} = 40\text{ V}$			-1	-0.18	
Output voltage recovery after output short circuit current	V_{OUT} (Recovery)	$V_{IN} = 4.25\text{ V}$, $R_L = 2.5\ \Omega$, $C_L = 20\ \mu\text{F}$	1, 2, 3	03, 04	1.2	1.3	V
		$V_{IN} = 4.25\text{ V}$, $R_L = 0.833\ \Omega$, $C_L = 20\ \mu\text{F}$		04	1.2	1.3	
		$V_{IN} = 40\text{ V}$, $R_L = 250\ \Omega$	1, 2, 3	03, 04	1.2	1.3	
Minimum load current	I_q	$V_{IN} = 4.25\text{ V}$, Forced $V_{OUT} = 1.4\text{ V}$	1, 2, 3	03	-3	-0.5	mA
		$V_{IN} = 14.25\text{ V}$, Forced $V_{OUT} = 1.4\text{ V}$			-3	-0.5	
		$V_{IN} = 41.25\text{ V}$, Forced $V_{OUT} = 1.4\text{ V}$			-5	-1	
		$V_{IN} = 4.25\text{ V}$, Forced $V_{OUT} = 1.4\text{ V}$		04	-3	-0.2	mA
		$V_{IN} = 14.25\text{ V}$, Forced $V_{OUT} = 1.4\text{ V}$			-3	-0.2	
		$V_{IN} = 41.25\text{ V}$, Forced $V_{OUT} = 1.4\text{ V}$			-5	-0.2	
Voltage start-up	V_{start}	$V_{IN} = 4.25\text{ V}$, $I_L = -500\text{ mA}$, $R_L = 2.5\ \Omega$, $C_L = 20\ \mu\text{F}$	1, 2, 3	03	1.2	1.3	V
		$V_{IN} = 4.25\text{ V}$, $I_L = -1.5\text{ A}$, $R_L = 0.833\ \Omega$, $C_L = 20\ \mu\text{F}$		04	1.2	1.3	
Output voltage <u>3/</u>	V_{OUT}	$V_{IN} = 6.25\text{ V}$, $I_L = -5\text{ mA}$	2	03, 04	1.2	1.3	V
Ripple rejection	$\Delta V_{IN}/\Delta V_{OUT}$	$V_{IN} = 6.25\text{ V}$, $I_L = -125\text{ mA}$, $e_i = 1\text{ V}_{rms}$ at 2400 Hz M,D,P,L,R	4	03	65		dB
					63		
		$V_{IN} = 6.25\text{ V}$, $I_L = -500\text{ mA}$, $e_i = 1\text{ V}_{rms}$ at 2400 Hz M,D,P,L,R		04	65		
				63			
Output noise voltage	V_{no}	$V_{IN} = 6.25\text{ V}$, $I_L = -50\text{ mA}$	7	03		120	μV_{rms}
		$V_{IN} = 6.25\text{ V}$, $I_L = -100\text{ mA}$		04		120	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions <u>1/ 2/</u> -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Line transient response	ΔV _{OUT} /ΔV _{IN}	V _{IN} = 6.25 V, ΔV _{IN} = 3 V, I _L = -10 mA	7	03		6	mV/V
				04		18 <u>6/</u>	mV
Load transient response	ΔV _{OUT} /ΔI _L	V _{IN} = 6.25 V, ΔI _L = -200 mA, I _L = -50 mA	7	03		0.6	mV/mA
				04		120 <u>7/</u>	mV

- 1/ Device types 01 and 02 have been characterized through all levels M, D, P of irradiation. However, these devices are only tested at the "P" level. Device types 03 and 04 have been characterized through all levels M, D, P, L, R of irradiation. However, these devices are only tested at the "R" level. Pre and Post irradiation values are identical unless otherwise specified in table I.
- 2/ These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits are for the conditions specified in MIL-STD-883, Method 1019 condition A.
- 3/ Tested at T_A = +125°C, correlated to T_A = +150°C.
- 4/ Limit is equivalent to a limit of 0.3 mV/mA.
- 5/ Limit is equivalent to a limit of 0.15 mV/mA.
- 6/ Limit of 6 mV/V is equivalent to 18 mV.
- 7/ Limit of 0.3 mV/V is equivalent to 120 mV.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-HDBK-103. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-973.

3.9 Verification and review for device class M. For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

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3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 52 (see MIL-PRF-38535, appendix A).

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

(2) $T_A = +125^\circ\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table IIA herein.

4.2.2 Additional criteria for device classes Q and V.

a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.

b. Interim and final electrical test parameters shall be as specified in table IIA herein.

c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-PRF-38535 permits alternate in-line control testing. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

a. Tests shall be as specified in table IIA herein.

b. Subgroups 5, 6, 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

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Case X

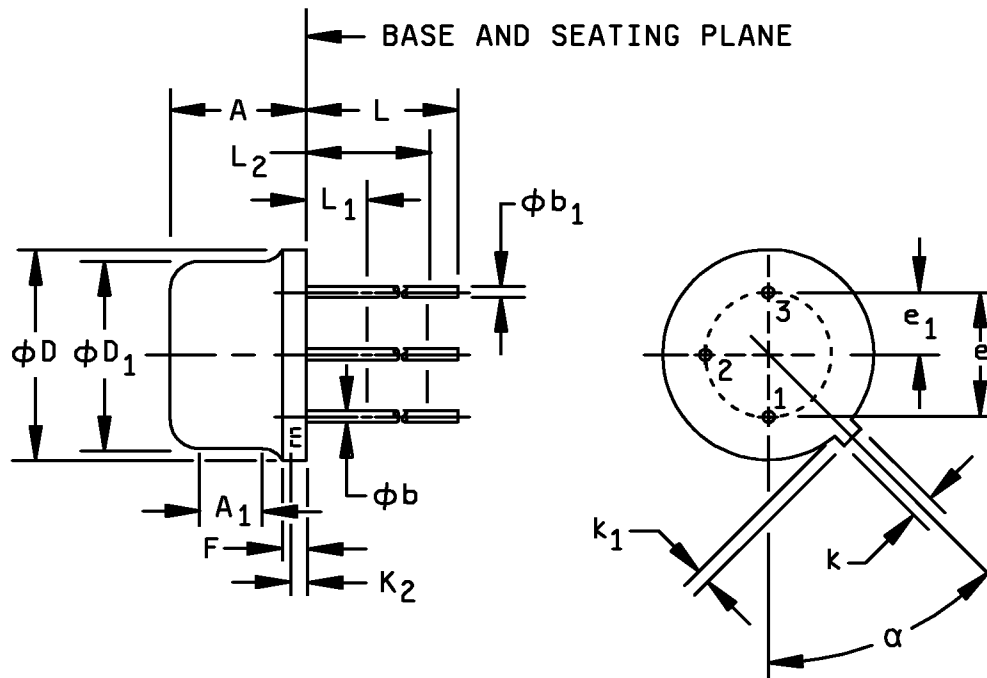


FIGURE 1. Case outline.

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Case X

Symbol	Inches		Millimeters		Notes
	Min	Max	Min	Max	
A	.165	.195	4.19	4.95	
A ₁	.100	----	2.54	----	7
φb	.016	.019	0.41	0.48	3
φb ₁	.016	.021	0.41	0.53	3
φD	.335	.370	8.51	9.40	
φD ₁	.305	.335	7.75	8.51	
e	.200 BSC		5.08 BSC		5
e ₁	.100 BSC		2.54 BSC		5
F	----	.050	----	1.27	
k	.028	.034	0.71	0.86	
k ₁	.029	.045	0.74	1.14	4
k ₂	.009	.041	0.23	1.04	
L	.500	----	12.70	----	
L ₁	----	.050	----	1.27	
L ₂	.250	----	6.35	----	
α	45° T.P.		45° T.P.		5

NOTES:

1. The US government preferred system of measurement is the metric SI system. However, this item was originally designed using inch-pound units of measurement. In the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.
2. φb applies between L₁ and beyond .500 inch (12.70 mm) from the seating plane (two leads). Diameter is uncontrolled in L₁ and beyond .500 inch (12.70 mm) from the seating plane.
3. Two leads.
4. Two holes.
5. Two holes located at true position within diameter .010 inch (0.25 mm).
6. Leads having a maximum diameter of .043 inch (1.09 mm) measured in gauging plane .054 inch (1.37 mm) ± .001 (0.03 mm) .000 inch (0.00 mm) below the seating plane shall be located at true position within diameter .014 inch (0.36 mm).
7. The mounting surface of the header shall be flat to convex within .003 inch (0.08 mm) inside a .930 inch (23.62 mm) diameter circle on the center of the header and flat to convex within .006 inch (0.15 mm) overall.

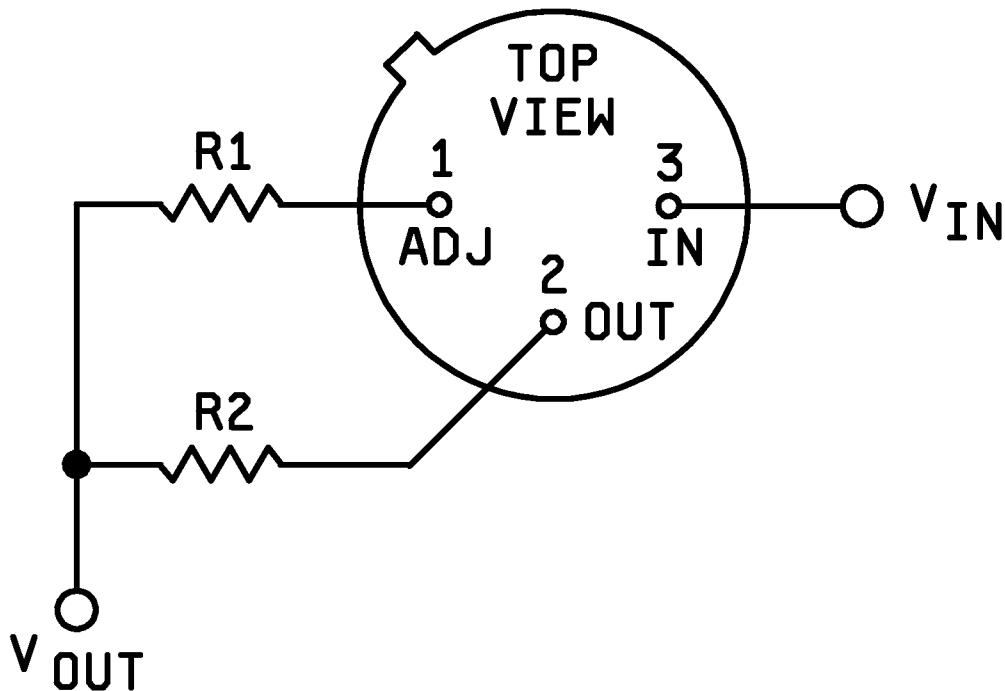
FIGURE 1. Case outline – Continued.

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Device type	01	02	03	04
Case outline	X	Y <u>1/</u>	X	Y <u>2/</u>
Terminal number	Terminal symbol			
1	ADJUSTMENT	ADJUSTMENT	INPUT	ADJUSTMENT
2	OUTPUT	OUTPUT	ADJUSTMENT	INPUT
3	INPUT	----	OUTPUT	----

1/ For case outline Y, case is input.
2/ For case outline Y, case is output.

FIGURE 2. Terminal connections.



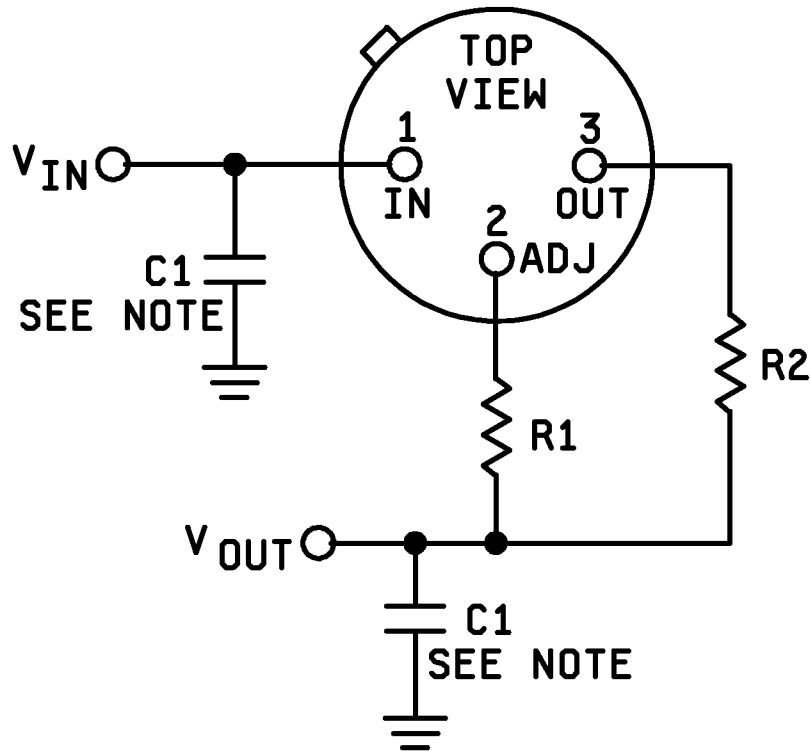
Device types 01 and 02

NOTES:

- $V_{OUT} = 13.5 \text{ V to } 16.5 \text{ V}$, $V_{IN} = -13.5 \text{ V to } 16.5 \text{ V}$
- $R1 = 1 \text{ k}\Omega$ 1/4 W, $R2 = 120 \Omega$ 1/4 W
- For case outline Y, case is input.

FIGURE 3. Radiation exposure circuit.

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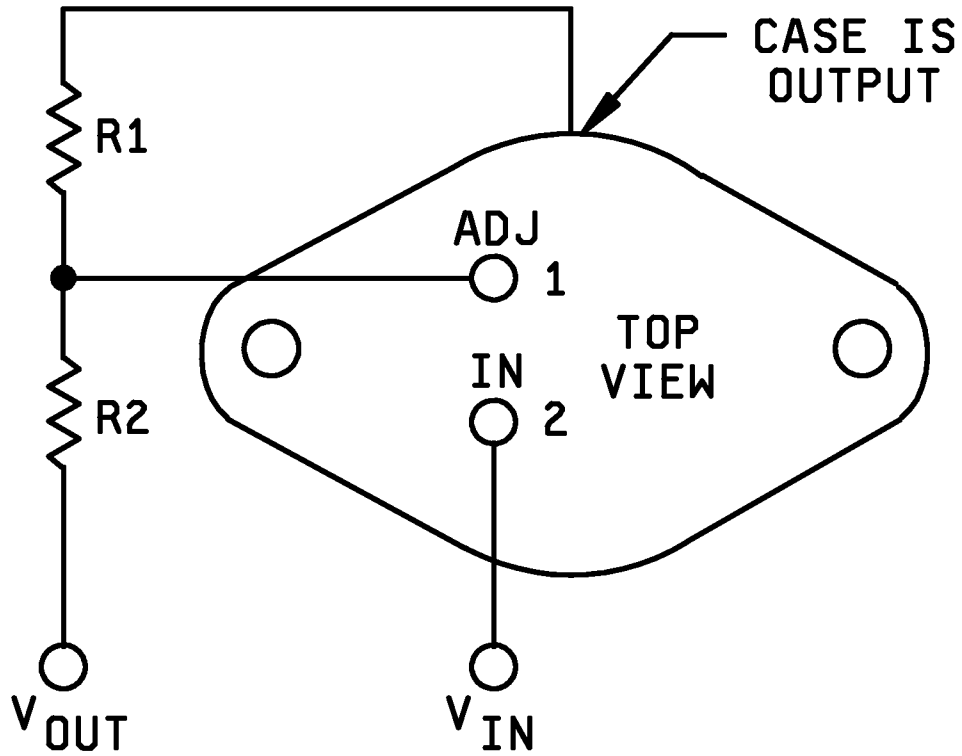
Device type 03

NOTES:

1. $V_{IN} = 15\text{ V to }17\text{ V}$, $V_{OUT} = -15\text{ V to }-17\text{ V}$
2. $R1 = 1\text{ k}\Omega\ \frac{1}{4}\text{ W}$, $R2 = 121\ \Omega\ \frac{1}{2}\text{ W}$, $C1 = 0.1\ \mu\text{F}$ (every 6th socket (min))

FIGURE 3. Radiation exposure circuit – Continued.

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Device type 04

NOTES:

1. $V_{IN} = 13.5\text{ V to }16.5\text{ V}$, $V_{OUT} = -13.5\text{ V to }-16.5\text{ V}$
2. $R1 = 150\ \Omega\ 1\text{ W}$, $R2 = 530\ \Omega\ 2\text{ W}$
3. Case is output

FIGURE 3. Radiation exposure circuit – Continued.

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TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical Parameters (see 4.2)	1	1	1
Final electrical Parameters (see 4.2)	1, 2, 3, 4 <u>1/</u>	1, 2, 3, 4 <u>1/</u>	1, 2, 3, 4 <u>1/</u>
Group A test Requirements (see 4.4)	1, 2, 3, 4, 7	1, 2, 3, 4, 7	1, 2, 3, 4, 7
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2,3	1, 2, 3 <u>2/</u>
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	1	1	1

1/ PDA applies to subgroup 1.

2/ Delta limits as specified in table IIB shall be required where specified, and the delta limits shall be computed with reference to the previous endpoint electrical parameters.

Table IIB. Group C end-point electrical parameters. $T_A = 25^\circ\text{C}$

Parameter	Device type	Conditions	Delta limit	
			Min	Max
V_{OUT}	01, 02	$V_{IN} = -4.25\text{ V}, I_L = 5\text{ mA}$	-0.01 V	0.01 V
	01	$V_{IN} = -4.25\text{ V}, I_L = 500\text{ mA}$	-0.01 V	0.01 V
	02	$V_{IN} = -4.25\text{ V}, I_L = 1.5\text{ A}$	-0.01 V	0.01 V
	01, 02	$V_{IN} = -41.25\text{ V}, I_L = 5\text{ mA}$	-0.01 V	0.01 V
	01	$V_{IN} = -41.25\text{ V}, I_L = 50\text{ mA}$	-0.01 V	0.01 V
	02	$V_{IN} = -41.25\text{ V}, I_L = 200\text{ mA}$	-0.01 V	0.01 V
	03, 04	$V_{IN} = 4.25\text{ V}, I_L = -5\text{ mA}$	-0.01 V	0.01 V
	03	$V_{IN} = 4.25\text{ V}, I_L = -500\text{ mA}$	-0.01 V	0.01 V
	04	$V_{IN} = 4.25\text{ V}, I_L = -1.5\text{ A}$	-0.01 V	0.01 V
	03, 04	$V_{IN} = 41.25\text{ V}, I_L = -5\text{ mA}$	-0.01 V	0.01 V
	03	$V_{IN} = 41.25\text{ V}, I_L = -50\text{ mA}$	-0.01 V	0.01 V
	04	$V_{IN} = 41.25\text{ V}, I_L = -200\text{ mA}$	-0.01 V	0.01 V
V_{rline}	01, 02	$V_{IN} = -41.25\text{ V to } -4.25\text{ V}, I_L = 5\text{ mA}$	-4 mV	4 mV
	03, 04	$V_{IN} = 4.25\text{ V to } 41.25\text{ V}, I_L = -5\text{ mA}$	-4 mV	4 mV
I_{adj}	01, 02	$V_{IN} = -4.25\text{ V}, I_L = 5\text{ mA}$	-10 μA	10 μA
		$V_{IN} = -41.25\text{ V}, I_L = 5\text{ mA}$	-10 μA	10 μA
	03, 04	$V_{IN} = 4.25\text{ V}, I_L = -5\text{ mA}$	-10 μA	10 μA
		$V_{IN} = 41.25\text{ V}, I_L = -5\text{ mA}$	-10 μA	10 μA
V_{OUT} (Recovery)	03	$V_{IN} = 4.25\text{ V}, R_L = 2.5\ \Omega, C_L = 20\ \mu\text{F}$	-0.01 V	0.01 V
		$V_{IN} = 40\text{ V}, R_L = 250\ \Omega$	-0.01 V	0.01 V

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4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
- b. $T_A = +125^\circ\text{C}$, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes M, Q, and V shall be as specified in MIL-PRF-38535. End-point electrical parameters shall be as specified in table IIA herein.

4.4.4.1 Total dose irradiation testing. Total dose irradiation testing shall be performed in accordance with MIL-STD-883 method 1019 condition A and as specified herein.

4.4.4.1.1 Accelerated aging test. Accelerated aging tests shall be performed on all devices requiring a RHA level greater than 5k rads(Si). The post-anneal end-point electrical parameter limits shall be as specified in table I herein and shall be the pre-irradiation end-point electrical parameter limit at $25^\circ\text{C} \pm 5^\circ\text{C}$. Testing shall be performed at initial qualification and after any design or process changes which may affect the RHA response of the device.

4.4.4.2 Dose rate burnout. When required by the customer test shall be performed on devices, SEC, or approved test structures at technology qualifications and after any design or process changes which may effect the RHA capability of the process. Dose rate burnout shall be performed in accordance with test method 1023 of MIL-STD-883 and as specified herein.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.1.2 Substitutability. Device class Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform Defense Supply Center Columbus when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0525.

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6.4 Comments. Comments on this drawing should be directed to DSCC-VA , Columbus, Ohio 43216-5000, or telephone (614) 692-0674.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.

6.6.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 99-11-15

Approved sources of supply for SMD 5962-99517 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
5962P9951701QXA	27014	LM137HPQML
5962P9951701VXA	27014	LM137HPQMLV
5962P9951702QYA	27014	LM137KPQML
5962P9951702VYA	27014	LM137KPQMLV
5962R9951703QXA	27014	LM117HRQML
5962R9951703VXA	27014	LM117HRQMLV
5962R9951704QYA	27014	LM117KRQML
5962R9951704VYA	27014	LM117KRQMLV

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE
number

27014

Vendor name
and address

National Semiconductor
2900 Semiconductor Drive
P.O. Box 58090
Santa Clara, CA 95052-8090

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